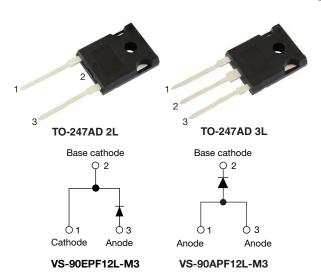


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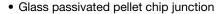
Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 90 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	90 A				
V _R	1200 V				
V _F at I _F	1.38 V				
I _{FSM}	1000 A				
t _{rr}	90 ns				
T _J max.	150 °C				
Package	TO-247AD 2L, TO-247AD 3L				
Circuit configuration	Single				
Snap factor	0.5				

FEATURES





 Low forward voltage drop and short reverse RoHS recovery time

COMPLIANT

 Designed qualified according JEDEC®-JESD 47

HALOGEN **FREE**

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-90EPF12L-M3, VS-90APF12L-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	TEST CONDITIONS	TEST CONDITIONS VALUES					
V _{RRM}		1200	V				
I _{F(AV)}	Sinusoidal waveform	90	Δ.				
I _{FSM}		100	A				
t _{rr}	1 A, - 100 A/μs	90	ns				
V _F	40 A, T _J = 25 °C	1.2	V				
T _J		-40 to +150	°C				

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-90EPF12L-M3	1200	1300	17
VS-90APF12L-M3	1200	1300	17

VS-90EPF12L-M3, VS-90APF12L-M3

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 106 °C, 180° conduction half sine wave	90			
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	850	Α		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	1000]		
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	3610	A ² s		
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 5100		A-S		
Maximum I²√t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	51 000	A²√s		

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS	
Maximum forward voltage drop	V_{FM}	90 A, T _J = 25 °C		1.38	V
Forward slope resistance	r _t	T _J = 150 °C		4.03	mΩ
Threshold voltage	V _{F(TO)}			0.87	V
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V - Patad V	0.1	mA
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	17	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	Is at 80 Apr	480	ns	I _{FM} t
Reverse recovery current	I _{rr}	I _F at 80 A _{pk} 25 Α/μs	7.1	Α	
Reverse recovery charge	Q _{rr}	25 °C	2.1	μC	dir/ Q _{rr}
Snap factor	S		0.5		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and stemperature range	storage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resist junction to case	ance,	R _{thJC}	DC operation	0.2	
Maximum thermal resist junction to ambient	Maximum thermal resistance, junction to ambient			40	°C/W
Typical thermal resistant case to heatsink	Typical thermal resistance, case to heatsink		Mounting surface, smooth and greased	0.25	
Approximate weight				6	g
Approximate weight				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque maximum				12 (10)	(lbf · in)
Marking device	Manding device		Case style TO-247AD 2L	90EP	F12L
ivial killy device			Case style TO-247AD 3L	90APF12L	



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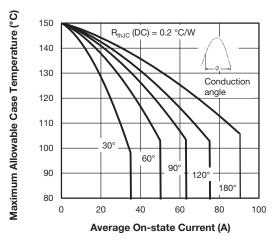


Fig. 1 - Current Rating Characteristics

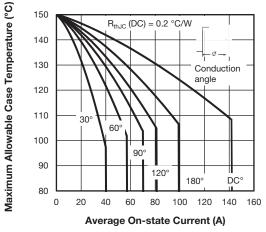


Fig. 2 - Current Rating Characteristics

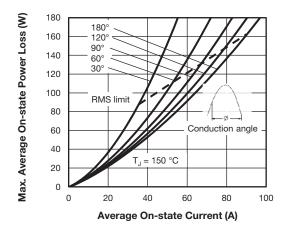


Fig. 3 - Forward Power Loss Characteristics

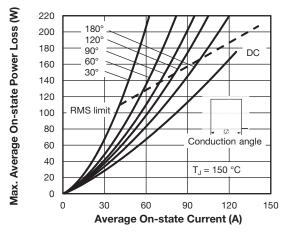


Fig. 4 - Forward Power Loss Characteristics

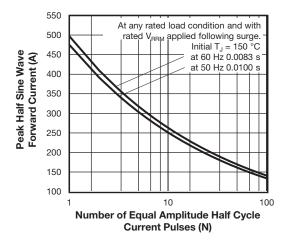


Fig. 5 - Maximum Non-Repetitive Surge Current

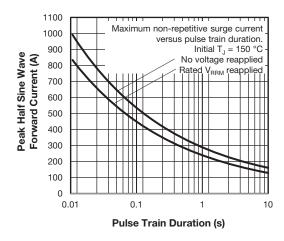


Fig. 6 - Maximum Non-Repetitive Surge Current

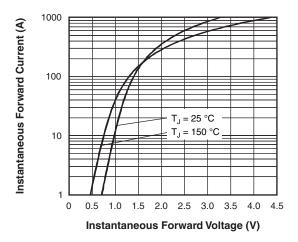


Fig. 7 - Forward Voltage Drop Characteristics

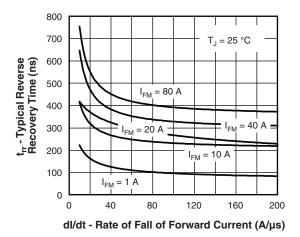


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

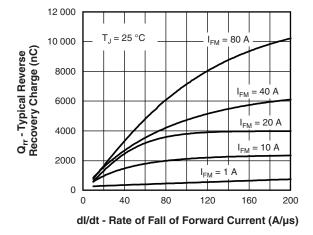


Fig. 10 - Recovery Charge Characteristics, $T_J = 25$ °C

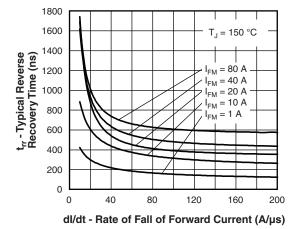


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

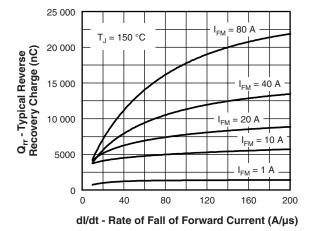


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



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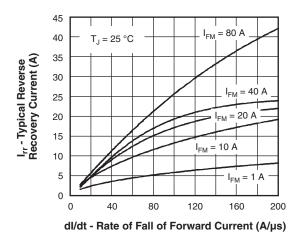


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

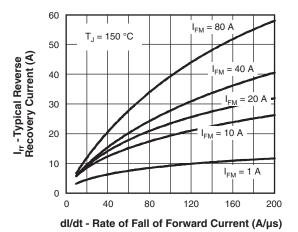


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

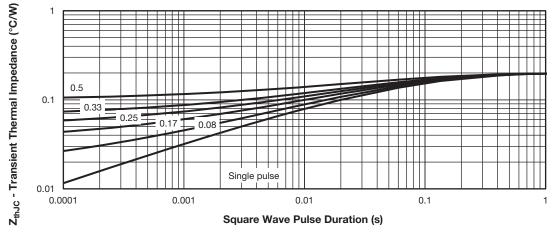


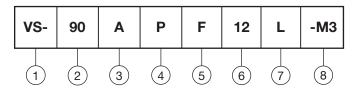
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-90EPF12L-M3, VS-90APF12L-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating (90 = 90 A)
- Circuit configuration: E = single, 2 pins
 - A = single, 3 pins
- 4 Package:
 - P = TO-247AD
- 5 Type of silicon:
 - F = fast recovery
- 6 Voltage code x 100 = V_{RRM} 12 = 1200 V
- 7 L = long lead
- 8 Environmental digit:
 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBES	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-90EPF12L-M3	25	500	Antistatic plastic tubes		
VS-90APF12L-M3	25	500	Antistatic plastic tubes		

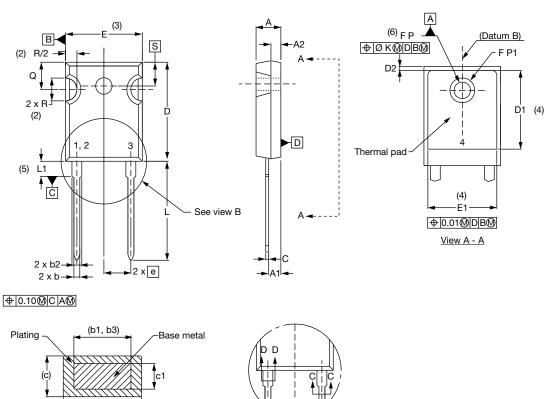
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536		
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Dort marking information	TO-247AD 2L	www.vishay.com/doc?95648		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		



Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	BSC	
ØK	0.254 0.010		10		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217 BSC		
	•		•	•	

Notes

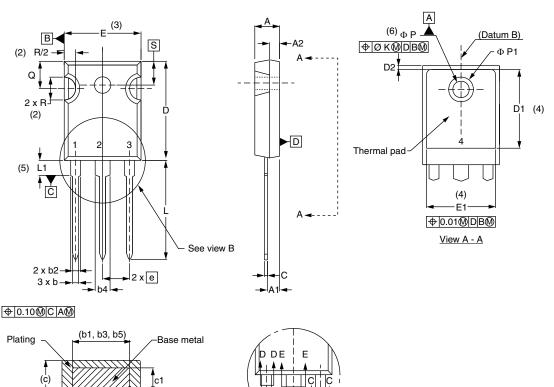
- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

Section C - C, D - D, E - E						
SYMBOL	MILLIN	IETERS	INC	NOTES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		
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• •			0.050			

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A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØК	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
		<u> </u>	<u> </u>	<u> </u>	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
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- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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